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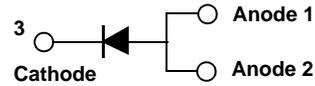
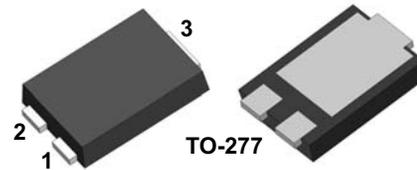
October 2016

FES6D - FES6J

6 A, 200 V - 600 V Surface Mount Ultrafast Rectifiers

Features

- Very Low Profile: Typical Height of 1.1 mm
 - Ultrafast Recovery Time
 - Low Forward Voltage Drop
 - Low Thermal Resistance
 - Very Stable Operation at Industrial temperature, 150 °C
 - RoHS Compliant
 - Green Molding Compound as per IEC61249 Standard
 - Lead Free in Compliance with EU RoHS 2011/65/EU Directive
 - Industrial Device Qualified per AEC-Q101 Standards
- * See authorized use policy



Ordering Information

Part Number	Top Mark	Package	Packing Method
FES6D	FES6D	TO-277 3L	Tape and Reel
FES6G	FES6G	TO-277 3L	Tape and Reel
FES6J	FES6J	TO-277 3L	Tape and Reel

FES6D - FES6J — 6 A, 200 V - 600 V Surface Mount Ultrafast Rectifiers

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value			Unit
		FES6D	FES6G	FES6J	
V_{RRM}	Repetitive Peak Reverse Voltage	200	400	600	V
$I_{F(AV)}$	Average Forward Rectified Current	6			A
I_{FSM}	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load	80			A
T_J	Operating Junction Temperature Range	-55 to +175			$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to +175			$^\circ\text{C}$

Thermal Characteristics⁽¹⁾

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
ψ_{JL}	Thermal Characteristics, Junction-to-Lead, Thermocouple Soldered to Cathode	6	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	100	$^\circ\text{C/W}$

Note:

1. Per JESD51-3 Recommended Thermal Test Board.

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Value			Unit
			FES6D	FES6G	FES6J	
V_F	Maximum Instantaneous Forward Voltage ⁽²⁾	$I_F = 6\text{ A}$	1.05	1.20	2.2	V
		$I_F = 6\text{ A}$, $T_J = 125^\circ\text{C}$	0.90	1.00	1.80	
I_R	Maximum Reverse Current at Rated V_R	$T_J = 25^\circ\text{C}$	2			μA
		$T_J = 125^\circ\text{C}$	200	500		
C_J	Typical Junction Capacitance	$V_R = 4\text{ V}$, $f = 1\text{ MHz}$	60		45	pF
T_{rr}	Typical Reverse Recovery Time	$I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{RR} = 0.25\text{ A}$	25			ns
		$I_F = 1\text{ A}$, $di/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	45			ns

Note:

2. Pulse test with $PW = 300\ \mu\text{s}$, 1% duty cycle

Typical Performance Characteristics

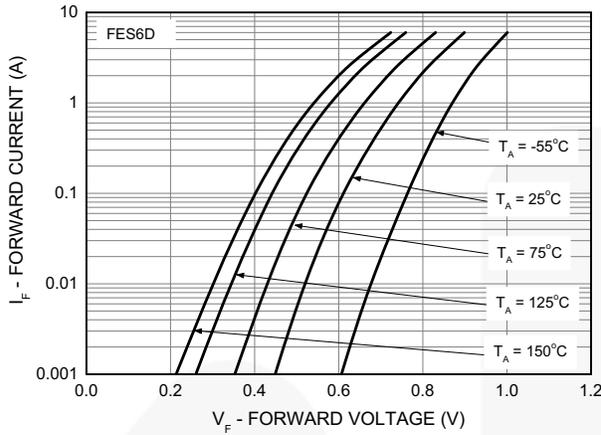


Fig 1. Typical Forward Characteristics for FES6D

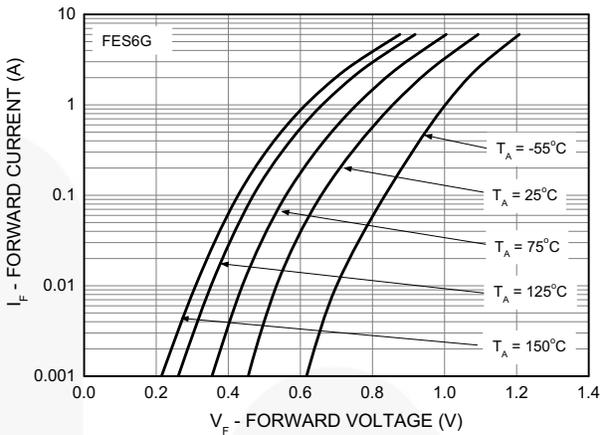


Fig 2. Typical Forward Characteristics for FES6G

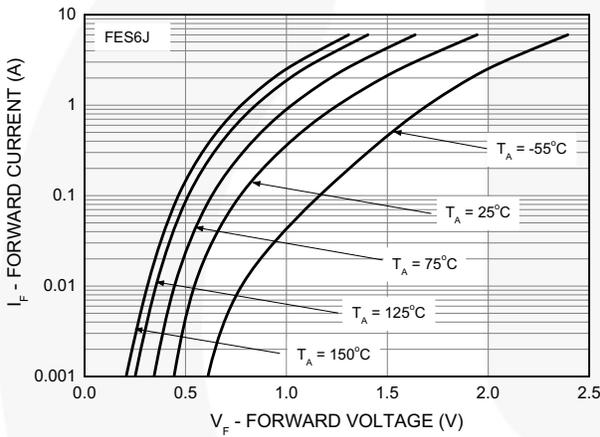


Fig 3. Typical Forward Characteristics for FES6J

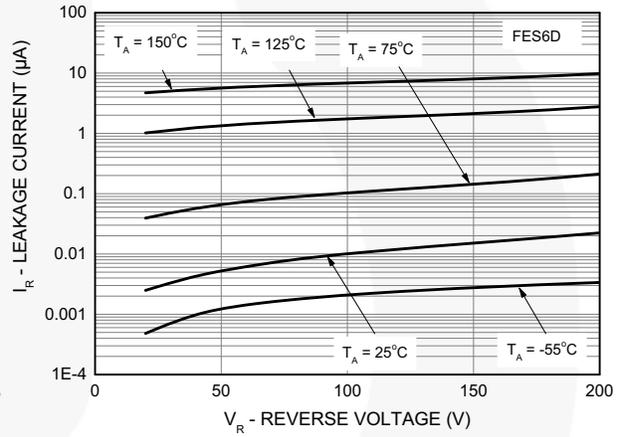


Fig 4. Typical Reverse Characteristics for FES6D

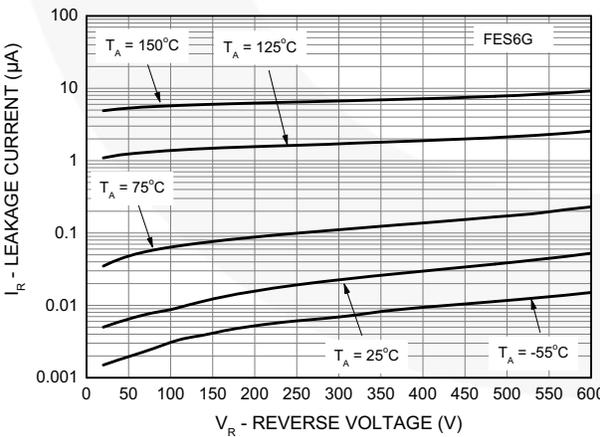


Fig 5. Typical Reverse Characteristics for FES6G

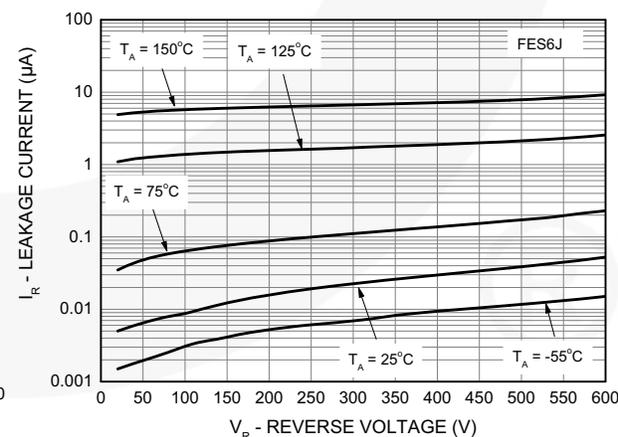


Fig 6. Typical Reverse Characteristics for FES6J

Typical Performance Characteristics (Continued)

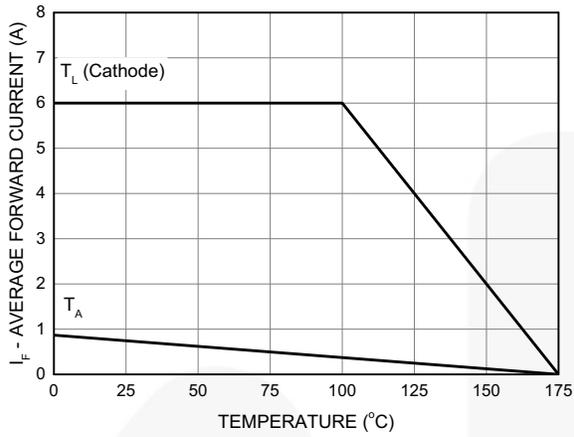


Fig 7. Forward Current Derating Curve

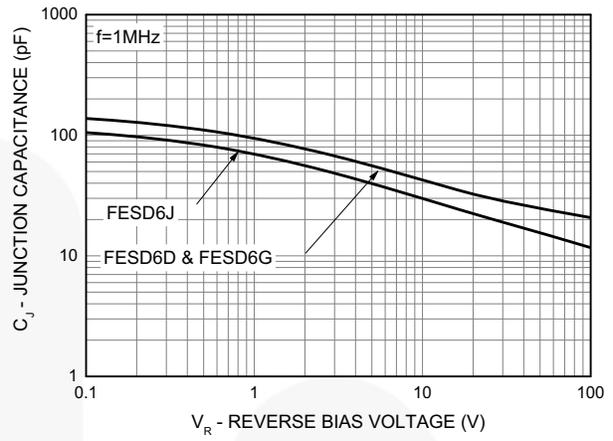
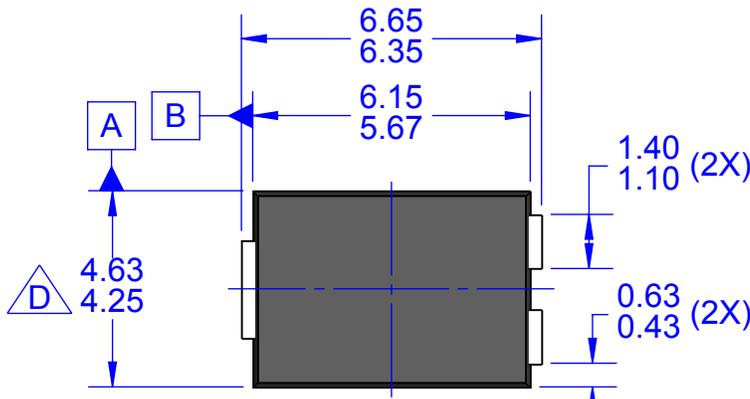
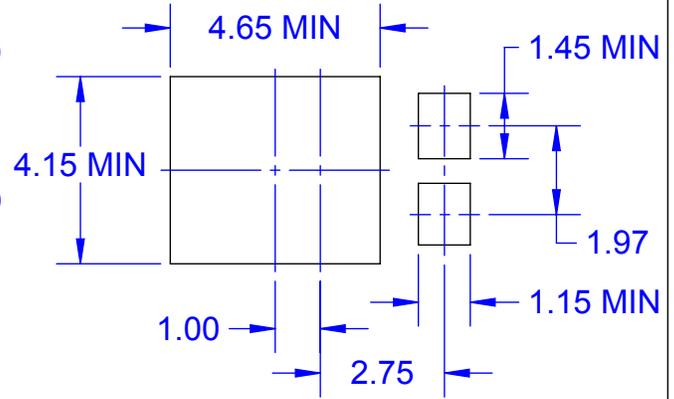


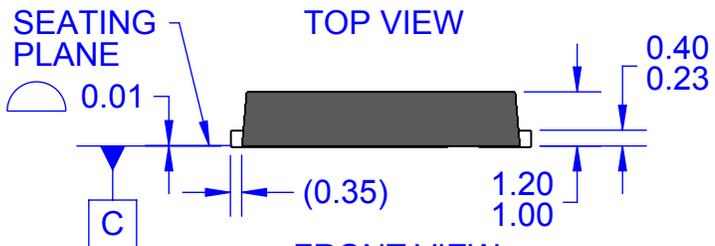
Fig 8. Typical Junction Capacitance



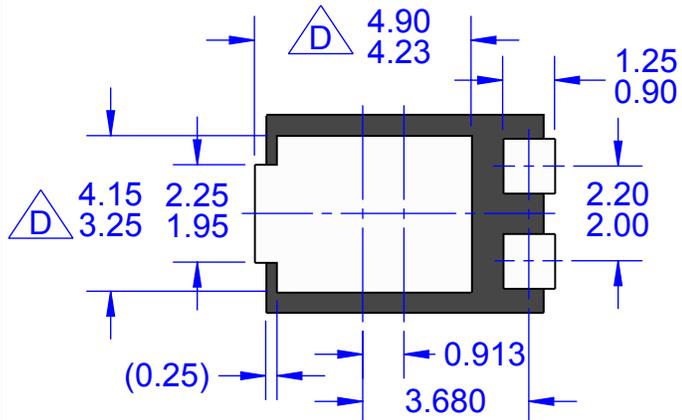
TOP VIEW



LAND PATTERN RECOMMENDATION



FRONT VIEW

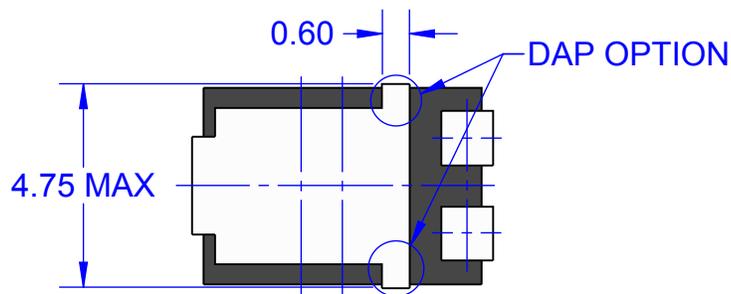


BOTTOM VIEW

NOTES: UNLESS OTHERWISE SPECIFIED

- A. PACKAGE REFERENCE: JEDEC TO-277
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.

- \triangle D DOES NOT COMPLY TO JEDEC STANDARD VALUE.
- E. DRAWING FILENAME: MKT-TO277A03rev5



BOTTOM VIEW - DAP OPTION



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